

VS-GB100LH120N

VS-GB100LH120N Information

Heisener.com	 VS-GB100LH120N Vishay Semiconductor Diodes Division Discrete Semiconductor Products Transistors - IGBTs - Modules IGBT 1200V 200A 833W INT-A-PAK Double INT-A-PAK (3 + 4) For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



VS-GB100LH120N Specifications

Manufacturer Part Number	VS-GB100LH120N	
Manufacturer	Vishay Semiconductor Diodes Division	
Category	Discrete Semiconductor Products	
	Transistors - IGBTs - Modules	
Package	Double INT-A-PAK (3 + 4)	
Series	-	
IGBT Type	-	
Configuration	Single	
Voltage - Collector Emitter Breakdown (Max)	1200V	
Current - Collector (Ic) (Max)	200A	
Power - Max	833W	
Vce(on) (Max) @ Vge, Ic	1.77V @ 15V, 100A (Typ)	
Current - Collector Cutoff (Max)	1mA	
Input Capacitance (Cies) @ Vce	8.96nF @ 25V	
Input	Standard	
NTC Thermistor	No	
Operating Temperature	-40°C ~ 150°C (TJ)	
Mounting Type	Chassis Mount	
Package / Case	Double INT-A-PAK (3 + 4)	
Supplier Device Package	Double INT-A-PAK	
	Report errors?	

VS-GB100LH120N Guarantees



Quality Guarantees

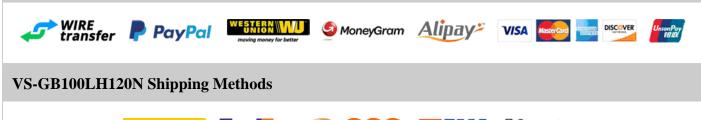
We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

VS-GB100LH120N Payment Methods





If you have any question about VS-GB100LH120N, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com